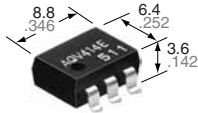
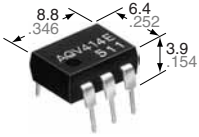
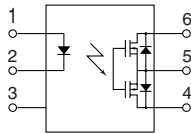


Normally closed 6-pin type
of 400V load voltage

PhotoMOS[®]
GU 1 Form B
(AQV414)



mm inch



RoHS compliant

FEATURES

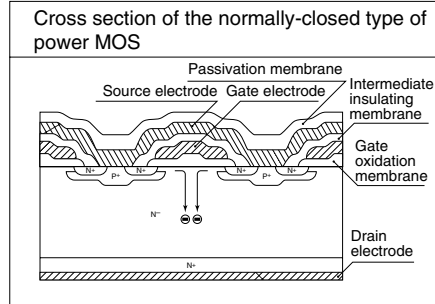
1. Low on-resistance (typ. 26Ω) for normally-closed type

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

3. High sensitivity and low on-resistance

Can control max. 0.15 A load current with 5 mA input current.

4. Low-level off state leakage current of max. 1 μA



2. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

TYPICAL APPLICATIONS

- Security equipment
- Telephone equipment (Dial pulse)
- Measuring instruments

TYPES

	I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity	
					Through hole terminal	Surface-mount terminal				
						Tube packing style	Tape and reel packing style		Tube	Tape and reel
Load voltage	Load current		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side						
AC/DC dual use	1,500 V AC	400 V	120 mA	DIP6-pin	AQV414	AQV414A	AQV414AX	AQV414AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

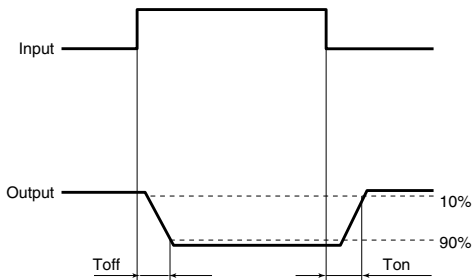
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	Type of connection	AQV414(A)	Remarks	
Input	LED forward current	I _F	50 mA		
	LED reverse voltage	V _R	5 V		
	Peak forward current	I _{FP}	1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	P _{in}	75 mW		
Output	Load voltage (peak AC)	V _L	400 V		
	Continuous load current	I _L	A	0.12 A	A connection: Peak AC, DC B, C connection: DC
			B	0.13 A	
			C	0.15 A	
	Peak load current	I _{peak}		0.3 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}		500 mW	
Total power dissipation	P _T		550 mW		
I/O isolation voltage	V _{iso}		1,500 V AC		
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F		

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV414(A)	Condition	
Input	LED operate (OFF) current	Typical	I _{off}	—	1.0 mA	
		Maximum				3.0 mA
	LED reverse (ON) current	Minimum	I _{on}	—	0.4 mA	
		Typical				0.95 mA
	LED dropout voltage	Typical	V _F	—	1.25 V (1.14 V at I _F = 5 mA)	I _F = 50 mA
		Maximum				
Output	On resistance	Typical	R _{on}	A	26 Ω	I _F = 0 mA I _L = Max. Within 1 s on time
		Maximum				
		Typical	R _{on}	B	20 Ω	
		Maximum				
	Typical	R _{on}	C	10 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
	Maximum					12.5 Ω
	Off state leakage current	Maximum	I _{Leak}	—	1 μA	I _F = 5 mA V _L = Max.
	Transfer characteristics	Operate (OFF) time*	Typical	T _{off}	—	0.47 ms
Maximum			1.0 ms			
Reverse (ON) time*		Typical	T _{on}	—	0.28 ms	I _F = 5 mA → 0 mA I _L = 120 mA
		Maximum				
I/O capacitance		Typical	C _{iso}	—	0.8 pF	f = 1 MHz V _B = 0 V
		Maximum				
Initial I/O isolation resistance	Minimum	R _{iso}	—	1,000 MΩ	500 V DC	

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	5	mA

- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

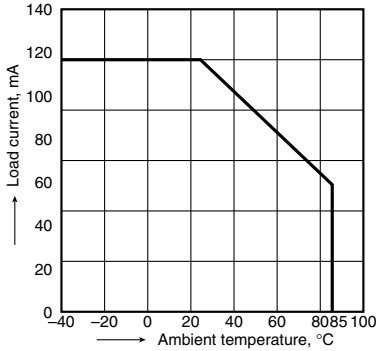
GU 1 Form B (AQV414)

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

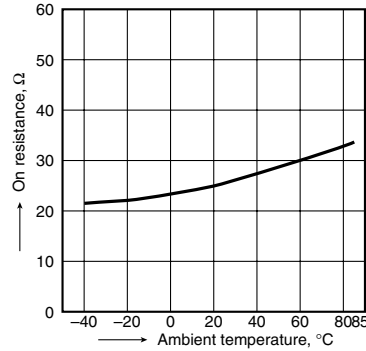
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$

Type of connection: A



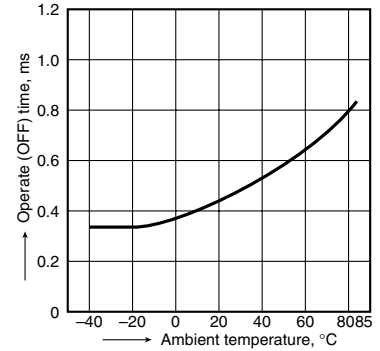
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
 LED current: 0 mA;
 Continuous load current: 120 mA (DC)



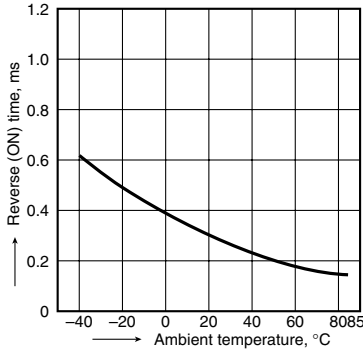
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA;
 Load voltage: 400 V (DC);
 Continuous load current: 120 mA (DC)



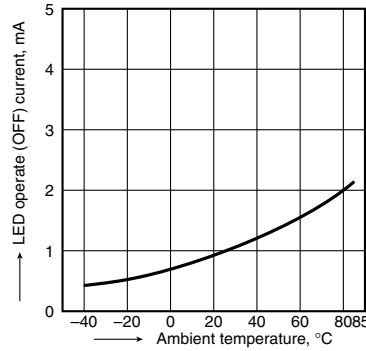
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC);
 Continuous load current: 120 mA (DC)



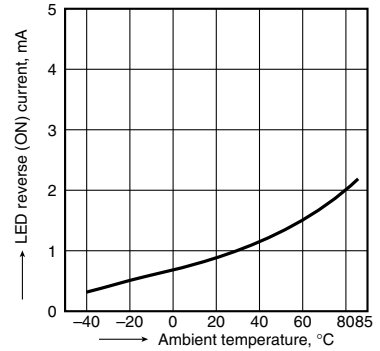
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
 Continuous load current: 120 mA (DC)



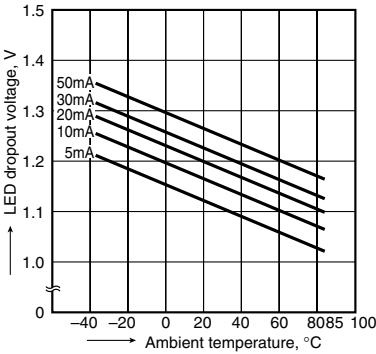
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
 Continuous load current: 120 mA (DC)



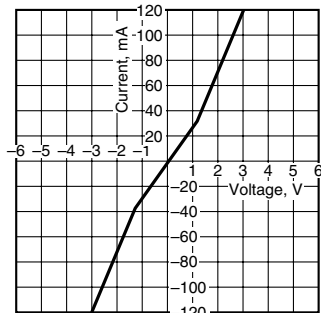
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



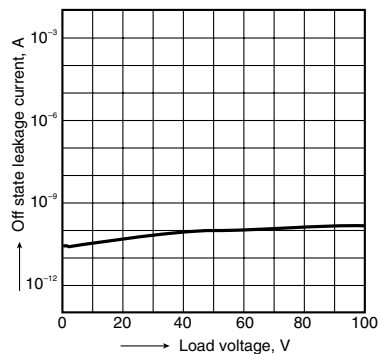
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
 Ambient temperature: 25°C 77°F



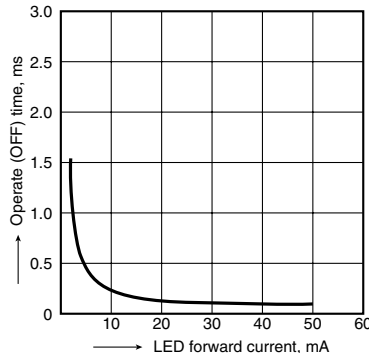
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
 LED current: 5 mA; Ambient temperature: 25°C 77°F



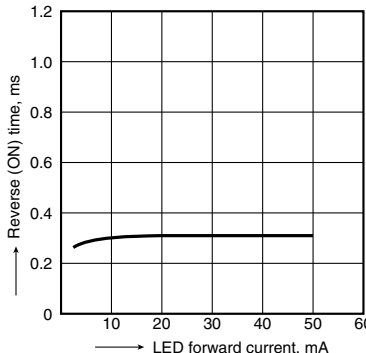
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
 Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
 Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
 Frequency: 1 MHz; Ambient temperature: 25°C 77°F

